

Quad Complementary CMOS Analog Switch

DESCRIPTION

The versatile DG213 analog switch has two NC and two NO switches. It can be used in various configurations, including four single-pole single-throw (SPST), two single-pole double-throw (SPDT), one "T" switch, one DPDT, etc. This device is fabricated in a Vishay Siliconix' proprietary high-voltage silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

This analog switch was designed for a wide variety of general purpose applications in telecommunications, instrumentation, process control, computer peripherals, etc. An improved charge injection compensation design minimizes switching transients. These switches can handle up to ± 22 V, and have an improved continuous current rating of 30 mA. An epitaxial layer prevents latchup.

All switches feature true bi-directional performance in the on condition, and will block signals to the supply levels in the off condition.

For additional information, please refer to Application Note AN208 (FaxBack document #70606).

FEATURES

- ± 22 V supply voltage rating
- TTL and CMOS compatible logic
- Low on-resistance - $r_{DS(on)}$: $45\ \Omega$
- Low leakage - $I_{D(on)}$: 20 pA
- Single supply operation possible
- Extended temperature range
- Fast switching - t_{ON} : 85 ns

BENEFITS

- Low charge injection - Q: 1 pC
- Wide analog signal range
- Simple logic interface
- Higher accuracy
- Minimum transients
- Reduced power consumption
- Low cost

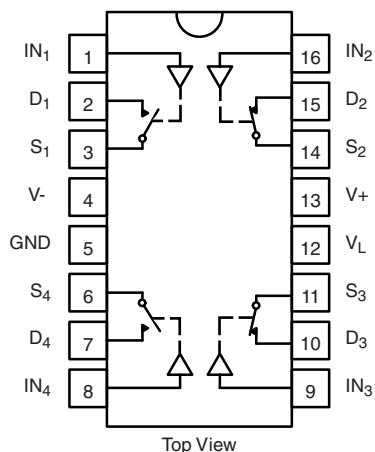
APPLICATIONS

- Industrial instrumentation
- Test equipment
- Communications systems
- Computer peripherals
- Portable instruments
- Sample-and-hold circuits



RoHS*
COMPLIANT

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

Logic	SW ₁ , SW ₄	SW ₂ , SW ₃
0	OFF	ON
1	ON	OFF

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

* Pb containing terminations are not RoHS compliant, exemptions may apply.

ORDERING INFORMATION

Temp. Range	Package	Standard Part Number	Lead (Pb)-free Part Number
- 40 °C to 85 °C	16-Pin Plastic DIP	DG213DJ	DG213DJ-E3
	16-Pin Narrow SOIC	DG213DY DG213DY-T1	DG213DY-E3 DG213DY-T1-E3
	16-Pin TSSOP	DG213DQ DG213DQ-T1	DG213DQ-E3 DG213DQ-T1-E3

ABSOLUTE MAXIMUM RATINGS $T_A = 25\text{ °C}$, unless otherwise noted

Parameter		Limit	Unit
Voltages Referenced V+ to V-		44	V
GND		25	
Digital Inputs ^a V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current, Any Terminal		30	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature		- 65 to 125	°C
Power Dissipation ^b	16-Pin Plastic DIP ^c	470	mW
	16-Pin Narrow SOIC ^d	640	
	16-Pin TSSOP ^d	500	

Notes:

- a. Signals on S_X , D_X , or IN_X exceeding V_+ or V_- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.5 mW/°C above 75 °C.
- d. Derate 7.6 mW/°C above 75 °C.



SPECIFICATIONS							
Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V, V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^e	Temp. ^a	D Suffix - 40 °C to 85 °C			Unit
				Min. ^c	Typ. ^b	Max. ^c	
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}		Full	V-		V+	V
Drain-Source On-Resistance	r _{DS(on)}	V _D = ± 10 V, I _S = 1 mA	Room Full		45	60 85	Ω
r _{DS(on)} Match	Δr _{DS(on)}		Room		1	2	
Source Off Leakage Current	I _{S(off)}	V _S = ± 14 V, V _D = ± 14 V	Room Full	- 0.5 - 5	± 0.01	0.5 5	nA
Drain Off Leakage Current	I _{D(off)}	V _D = ± 14 V, V _S = ± 14 V	Room Full	- 0.5 - 5	± 0.01	0.5 5	
Drain On Leakage Current ^f	I _{D(on)}	V _S = V _D = 14 V	Room Full	- 0.5 - 10	± 0.02	0.5 10	
Digital Control							
Input Voltage High	V _{INH}		Full	2.4			V
Input Voltage Low	V _{INL}		Full			0.8	
Input Current	I _{INL} or I _{INH}	V _{INH} or V _{INL}	Full	- 1		1	μA
Input Capacitance	C _{IN}		Room		5		pF
Dynamic Characteristics							
Turn-On Time	t _{ON}	V _S = 10 V See Figure 2	Room		85	130	ns
Turn-Off Time	t _{OFF}		Room		55	100	
Break-Before-Make Time Delay	t _D	V _S = 10 V, See Figure 3	Room	15	25		
Charge Injection	Q	C _L = 1000 pF, V _g = 0 V, R _g = 0 Ω	Room		1		pC
Source-Off Capacitance	C _{S(off)}	V _S = 0 V, f = 1 MHz	Room		5		pF
Drain-Off Capacitance	C _{D(off)}		Room		5		
Channel On Capacitance	C _{D(on)}	V _D = V _S = 0 V, f = 1 MHz	Room		16		
Off-Isolation	OIRR	C _L = 15 pF, R _L = 50 Ω V _S = 1 V _{RMS} , f = 100 kHz	Room		90		dB
Channel-to-Channel Crosstalk	X _{TALK}		Room		95		
Power Supply							
Positive Supply Current	I+	V _{IN} = 0 or 5 V	Room Full			1 5	μA
Negative Supply Current	I-		Room Full	- 1 - 5			
Logic Supply Current	I _L		Room Full			1 5	
Power Supply Range for Continuous Operation	V _{OP}		Full	± 3		± 22	V

SPECIFICATIONS for Unipolar Supply							
Parameter	Symbol	Test Conditions Unless Otherwise Specified V ₊ = 12 V, V ₋ = 0 V, V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^e	Temp. ^a	D Suffix - 40 °C to 85 °C			Unit
				Min. ^c	Typ. ^b	Max. ^c	
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}		Full	V-		V+	V
Drain-Source On-Resistance	r _{DS(on)}	V _D = 3 V, I _S = 1 mA	Room Full		90	110 140	Ω
Dynamic Characteristics							
Turn-On Time	t _{ON}	See Figure 2	Room		125	200	ns
Turn-Off Time	t _{OFF}		Room		45	100	
Break-Before-Make Time Delay	t _D	V _S = 8 V, See Figure 3	Room	50	80		
Charge Injection	Q	C _L = 1 nF, V _{gen} = 6 V, R _{gen} = 0 Ω	Room		4		pC
Power Supply							
Positive Supply Current	I ₊	V _{IN} = 0 or 5 V	Room Full			1 5	μA
Negative Supply Current	I ₋		Room Full	- 1 - 5			
Logic Supply Current	I _L		Room Full			1 5	
Power Supply Range for Continuous Operation	V _{OP}		Full	+ 3		+ 40	V

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

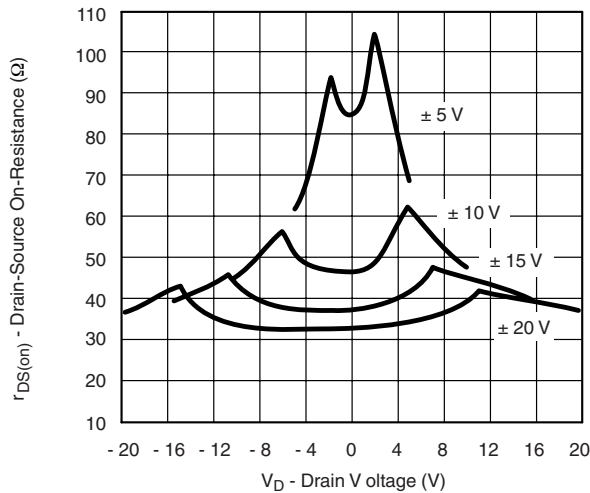
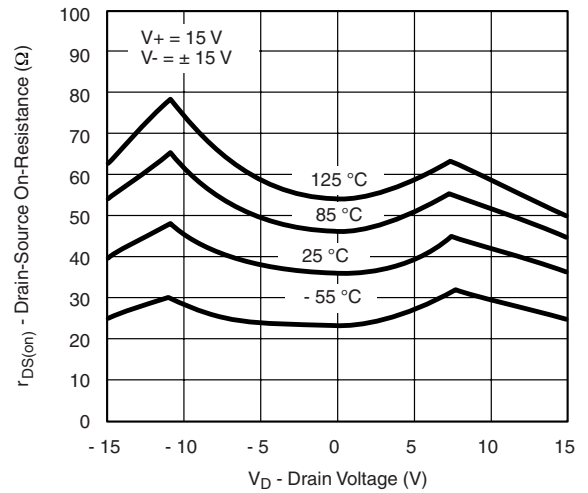
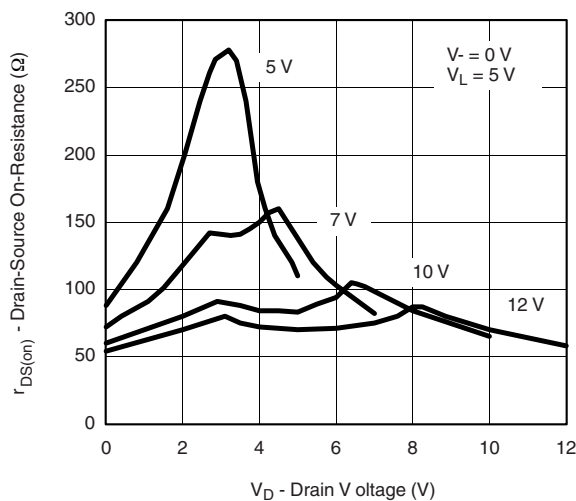
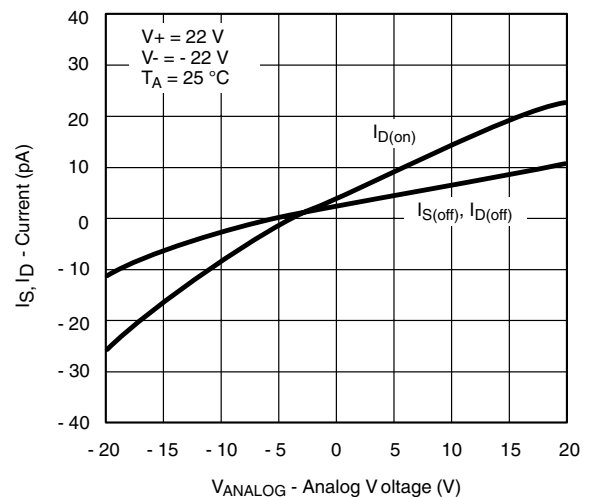
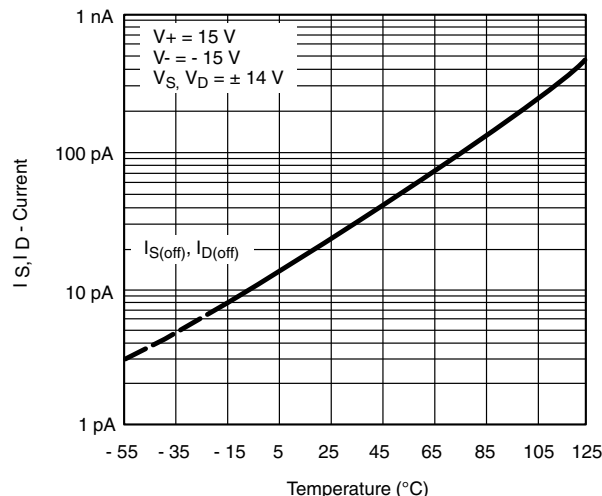
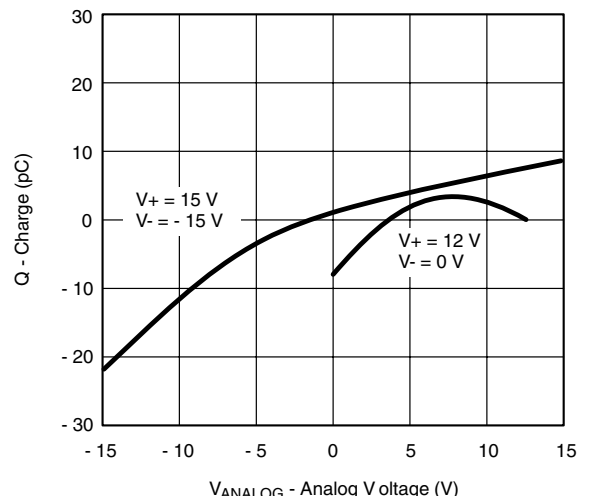
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

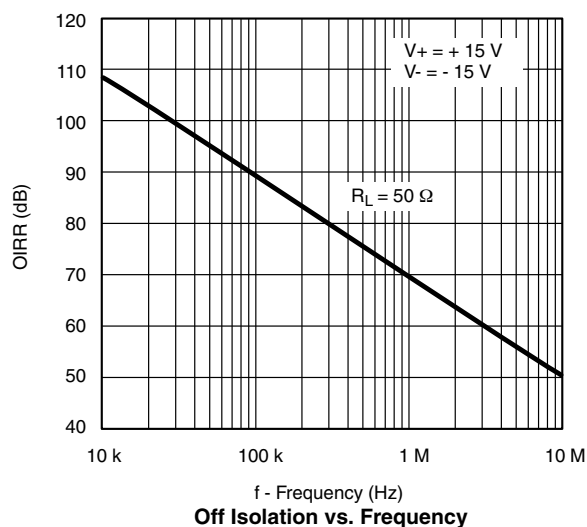
d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted

 $r_{DS(on)}$ vs. V_D and Power Supply Voltages

 $r_{DS(on)}$ vs. V_D and Temperature

 $r_{DS(on)}$ vs. V_D and Single Power Supply Voltages

Leakage Currents vs. Analog Voltage

Leakage Current vs. Temperature

 Q_S , Q_D - Charge Injection vs. Analog Voltage

TYPICAL CHARACTERISTICS $T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted



SCHEMATIC DIAGRAM Typical Channel

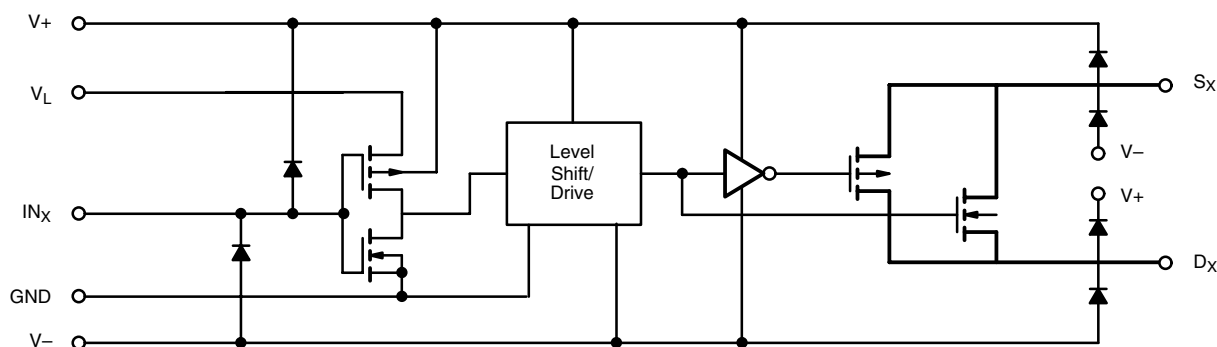


Figure 1.

TEST CIRCUITS

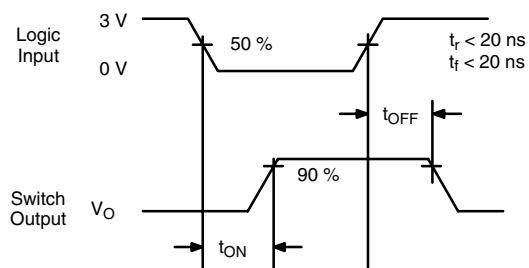
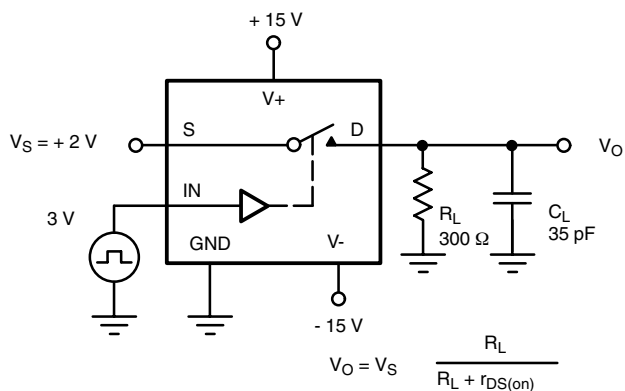
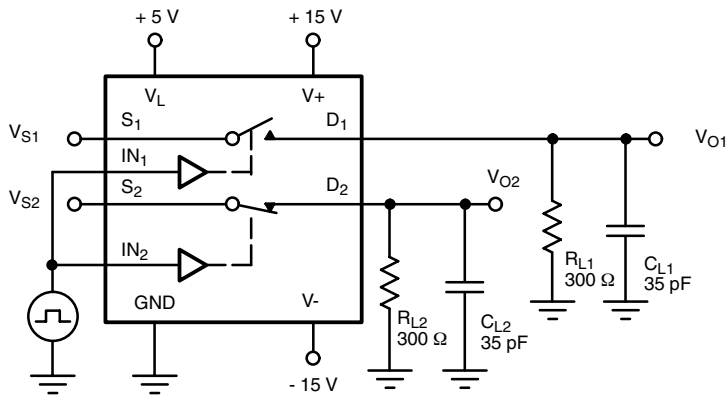
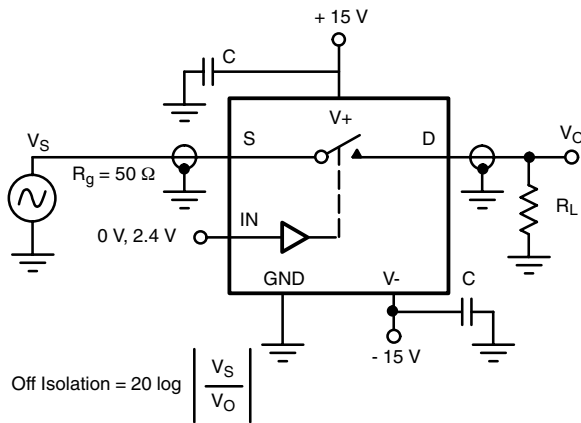
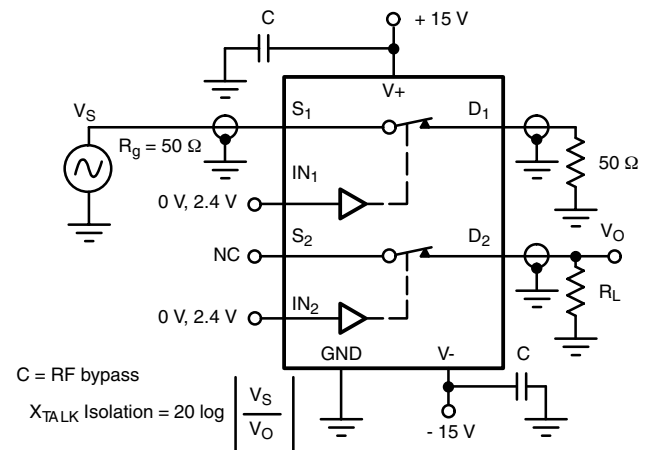
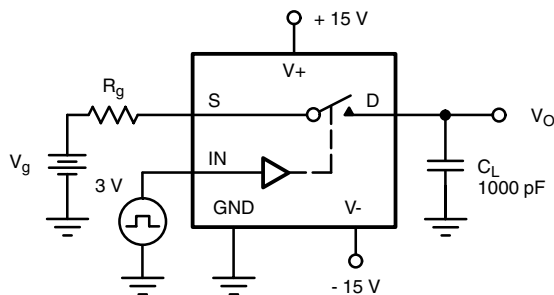
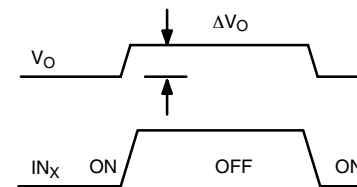


Figure 2. Switching Time

TEST CIRCUITS


C_L (includes fixture and stray capacitance)

Figure 3. Break-Before-Make

Figure 4. Off Isolation

Figure 5. Channel-to-Channel Crosstalk

Figure 6. Charge Injection


ΔV_O = measured voltage error due to charge injection
The charge injection in coulombs is $Q = C_L \times \Delta V_O$

APPLICATIONS

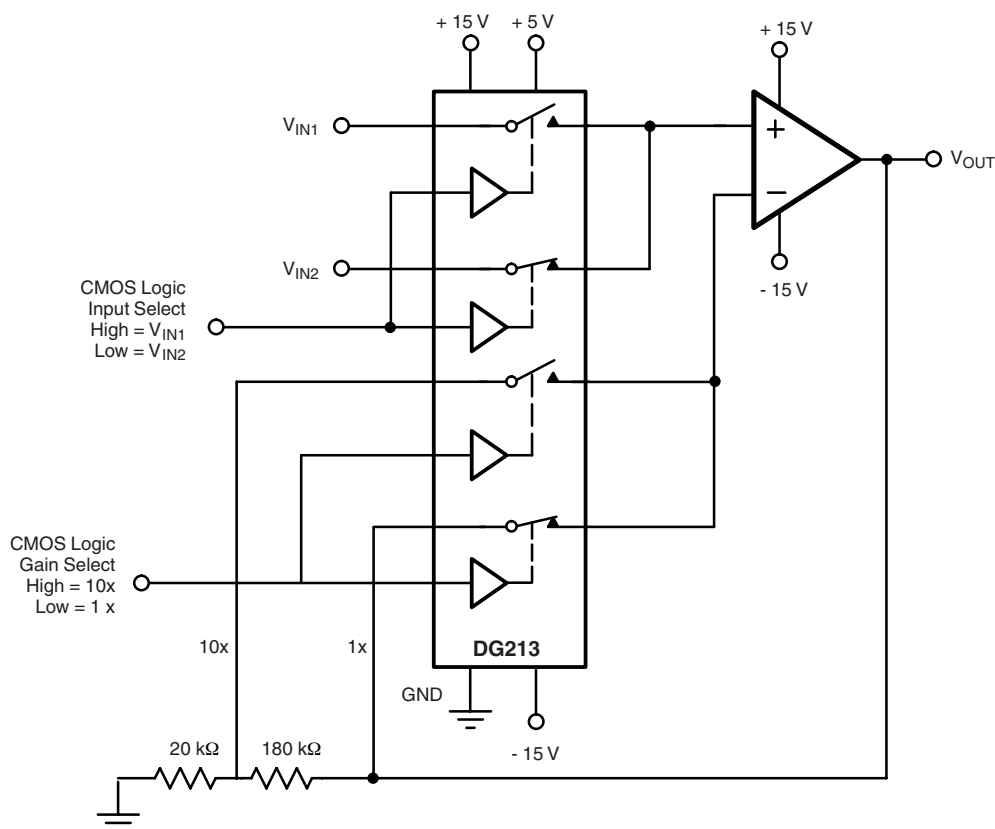


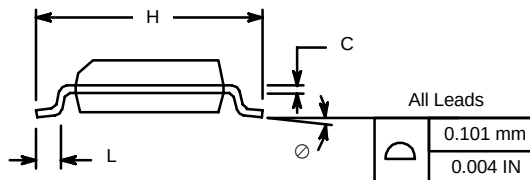
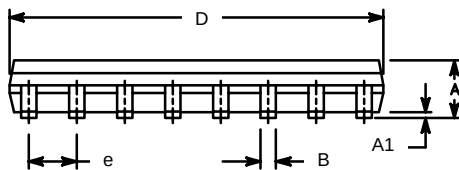
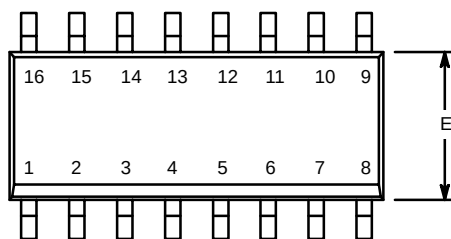
Figure 7. Low Power Non-Inverting Amplifier with Digitally Selectable Inputs and Gain

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <http://www.vishay.com/ppg?70662>.



SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012

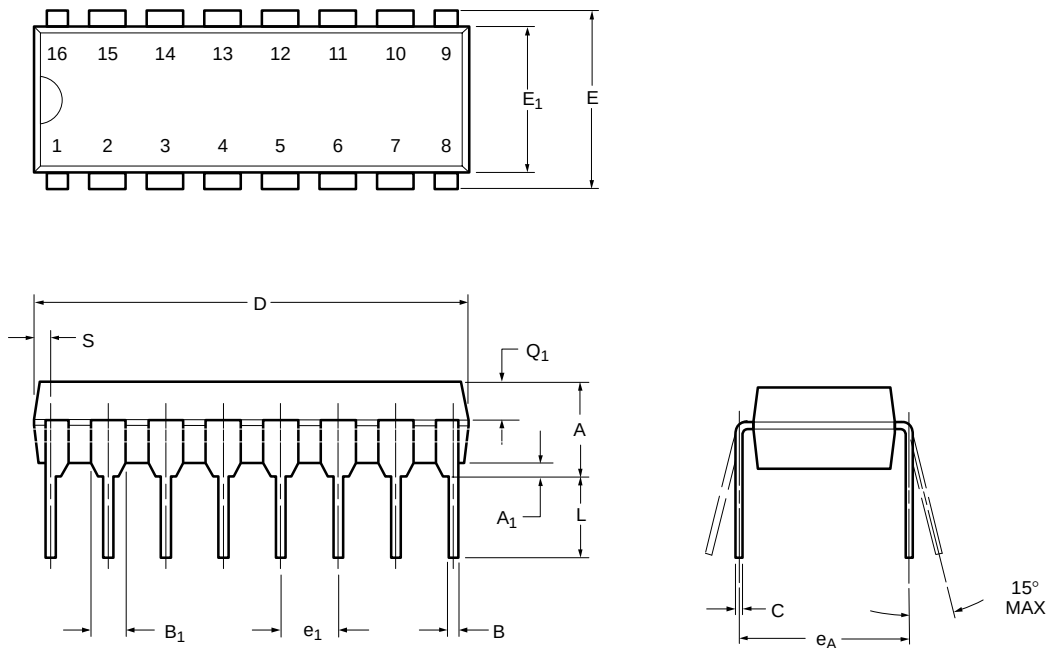


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300

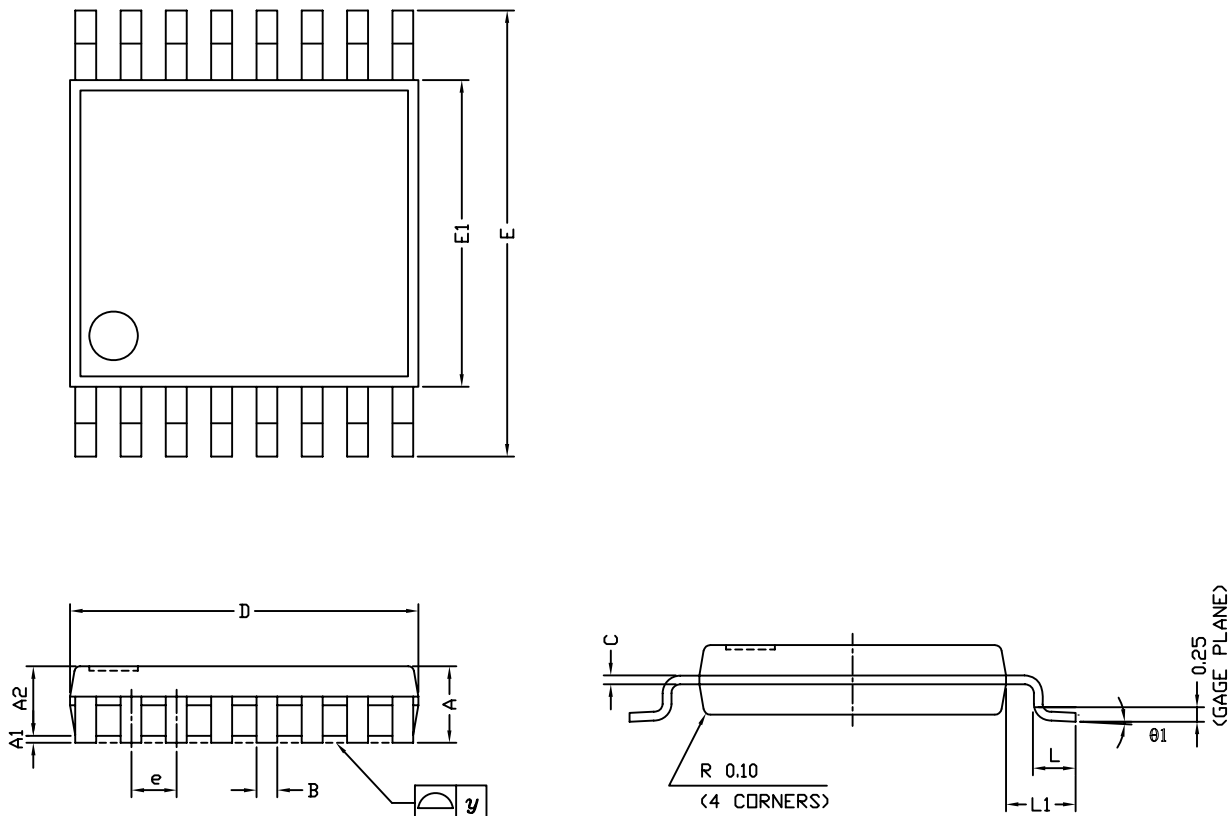


PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E₁	5.59	7.11	0.220	0.280
e₁	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482				

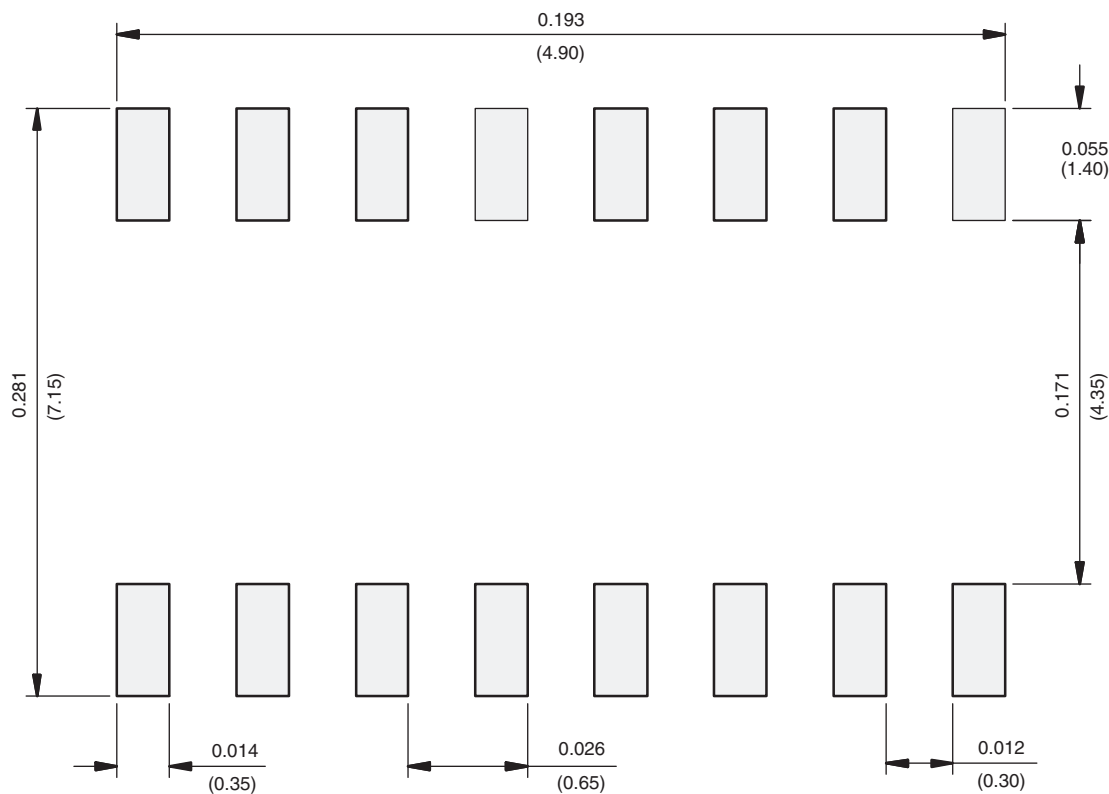
TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			

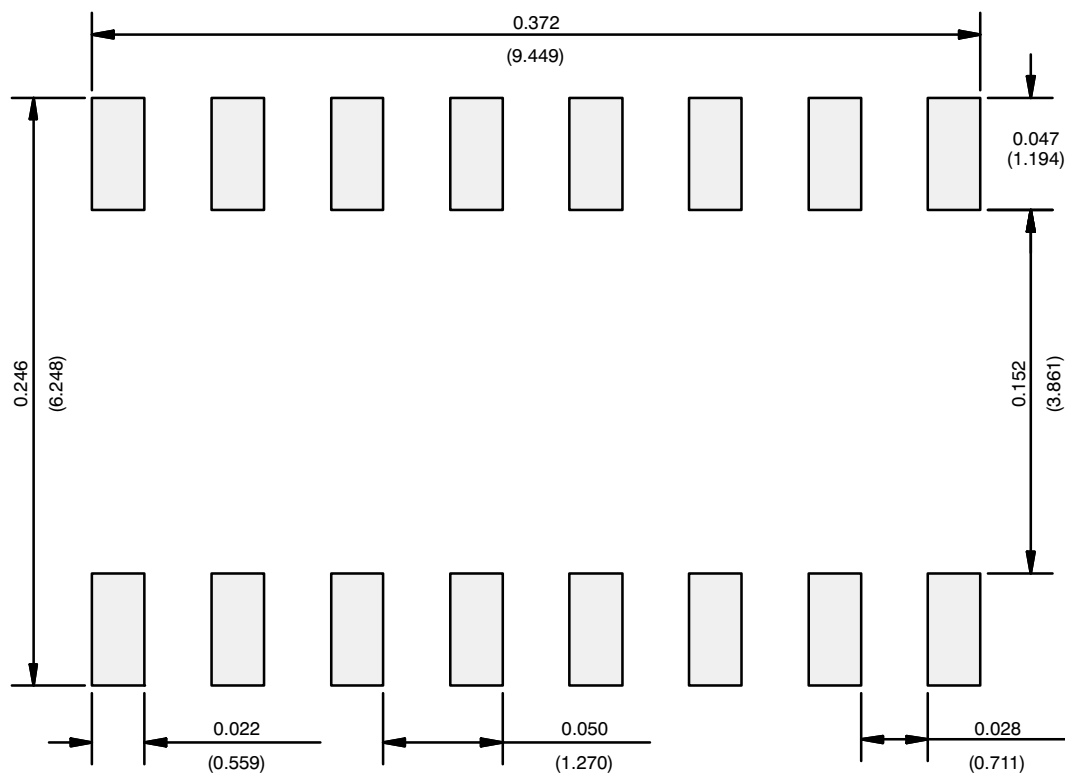


RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9